E·XFL



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Understanding <u>Embedded - FPGAs (Field</u> <u>Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	6144
Total RAM Bits	36864
Number of I/O	68
Number of Gates	250000
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	-20°C ~ 85°C (TJ)
Package / Case	100-TQFP
Supplier Device Package	100-VQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/agln250v5-vqg100

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



The inputs of the six CCC blocks are accessible from the FPGA core or from dedicated connections to the CCC block, which are located near the CCC.

The CCC block has these key features:

- Wide input frequency range (f_{IN CCC}) = 1.5 MHz up to 250 MHz
- Output frequency range (f_{OUT CCC}) = 0.75 MHz up to 250 MHz
- 2 programmable delay types for clock skew minimization
- Clock frequency synthesis (for PLL only)

Additional CCC specifications:

- Internal phase shift = 0°, 90°, 180°, and 270°. Output phase shift depends on the output divider configuration (for PLL only).
- Output duty cycle = 50% ± 1.5% or better (for PLL only)
- Low output jitter: worst case < 2.5% × clock period peak-to-peak period jitter when single global network used (for PLL only)
- Maximum acquisition time is 300 µs (for PLL only)
- Exceptional tolerance to input period jitter—allowable input jitter is up to 1.5 ns (for PLL only)
- Four precise phases; maximum misalignment between adjacent phases of 40 ps \times 250 MHz / f_{OUT_CCC} (for PLL only)

Global Clocking

IGLOO nano devices have extensive support for multiple clocking domains. In addition to the CCC and PLL support described above, there is a comprehensive global clock distribution network.

Each VersaTile input and output port has access to nine VersaNets: six chip (main) and three quadrant global networks. The VersaNets can be driven by the CCC or directly accessed from the core via multiplexers (MUXes). The VersaNets can be used to distribute low-skew clock signals or for rapid distribution of high-fanout nets.

I/Os with Advanced I/O Standards

IGLOO nano FPGAs feature a flexible I/O structure, supporting a range of voltages (1.2 V, 1.2 V wide range, 1.5 V, 1.8 V, 2.5 V, 3.0 V wide range, and 3.3 V).

The I/Os are organized into banks with two, three, or four banks per device. The configuration of these banks determines the I/O standards supported.

Each I/O module contains several input, output, and enable registers. These registers allow the implementation of various single-data-rate applications for all versions of nano devices and double-data-rate applications for the AGLN060, AGLN125, and AGLN250 devices.

IGLOO nano devices support LVTTL and LVCMOS I/O standards, are hot-swappable, and support cold-sparing and Schmitt trigger.

Hot-swap (also called hot-plug, or hot-insertion) is the operation of hot-insertion or hot-removal of a card in a powered-up system.

Cold-sparing (also called cold-swap) refers to the ability of a device to leave system data undisturbed when the system is powered up, while the component itself is powered down, or when power supplies are floating.

Wide Range I/O Support

IGLOO nano devices support JEDEC-defined wide range I/O operation. IGLOO nano devices support both the JESD8-B specification, covering both 3 V and 3.3 V supplies, for an effective operating range of 2.7 V to 3.6 V, and JESD8-12 with its 1.2 V nominal, supporting an effective operating range of 1.14 V to 1.575 V.

Wider I/O range means designers can eliminate power supplies or power conditioning components from the board or move to less costly components with greater tolerances. Wide range eases I/O bank management and provides enhanced protection from system voltage spikes, while providing the flexibility to easily run custom voltage applications.

Specifying I/O States During Programming

You can modify the I/O states during programming in FlashPro. In FlashPro, this feature is supported for PDB files generated from Designer v8.5 or greater. See the *FlashPro User's Guide* for more information.

- Note: PDB files generated from Designer v8.1 to Designer v8.4 (including all service packs) have limited display of Pin Numbers only.
 - 1. Load a PDB from the FlashPro GUI. You must have a PDB loaded to modify the I/O states during programming.
 - 2. From the FlashPro GUI, click PDB Configuration. A FlashPoint Programming File Generator window appears.
 - 3. Click the Specify I/O States During Programming button to display the Specify I/O States During Programming dialog box.
 - 4. Sort the pins as desired by clicking any of the column headers to sort the entries by that header. Select the I/Os you wish to modify (Figure 1-7 on page 1-9).
 - Set the I/O Output State. You can set Basic I/O settings if you want to use the default I/O settings for your pins, or use Custom I/O settings to customize the settings for each pin. Basic I/O state settings:

1 - I/O is set to drive out logic High

0 - I/O is set to drive out logic Low

Last Known State – I/O is set to the last value that was driven out prior to entering the programming mode, and then held at that value during programming

Z -Tri-State: I/O is tristated

Figure 1-7 • I/O States During Programming Window



IGLOO nano Device Overview

- 6. Click **OK** to return to the FlashPoint Programming File Generator window.
- Note: I/O States During programming are saved to the ADB and resulting programming files after completing programming file generation.

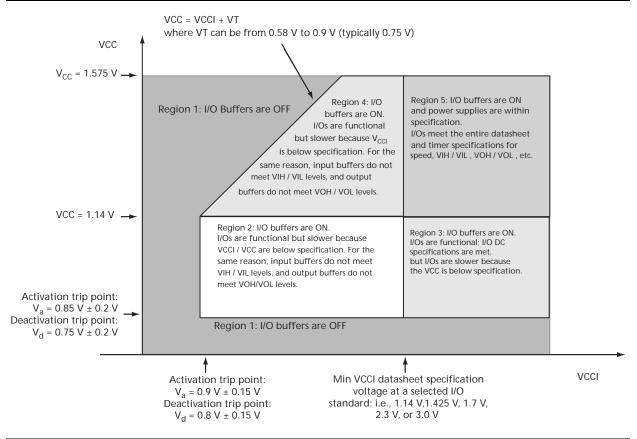


Figure 2-2 • V2 Devices – I/O State as a Function of VCCI and VCC Voltage Levels

IGLOO nano DC and Switching Characteristics

Guidelines

Toggle Rate Definition

A toggle rate defines the frequency of a net or logic element relative to a clock. It is a percentage. If the toggle rate of a net is 100%, this means that this net switches at half the clock frequency. Below are some examples:

- The average toggle rate of a shift register is 100% because all flip-flop outputs toggle at half of the clock frequency.
- The average toggle rate of an 8-bit counter is 25%:
 - Bit 0 (LSB) = 100%
 - Bit 1 = 50%
 - Bit 2 = 25%
 - ...
 - Bit 7 (MSB) = 0.78125%
 - Average toggle rate = (100% + 50% + 25% + 12.5% + . . . + 0.78125%) / 8

Enable Rate Definition

Output enable rate is the average percentage of time during which tristate outputs are enabled. When nontristate output buffers are used, the enable rate should be 100%.

Table 2-19 • Toggle Rate Guidelines Recommended for Power Calculation

Component	Definition	Guideline
α_1	Toggle rate of VersaTile outputs	10%
α ₂	I/O buffer toggle rate	10%

Table 2-20 • Enable Rate Guidelines Recommended for Power Calculation

Component	Definition	Guideline
β ₁	I/O output buffer enable rate	100%
β ₂	RAM enable rate for read operations	12.5%
β ₃	RAM enable rate for write operations	12.5%

IGLOO nano DC and Switching Characteristics

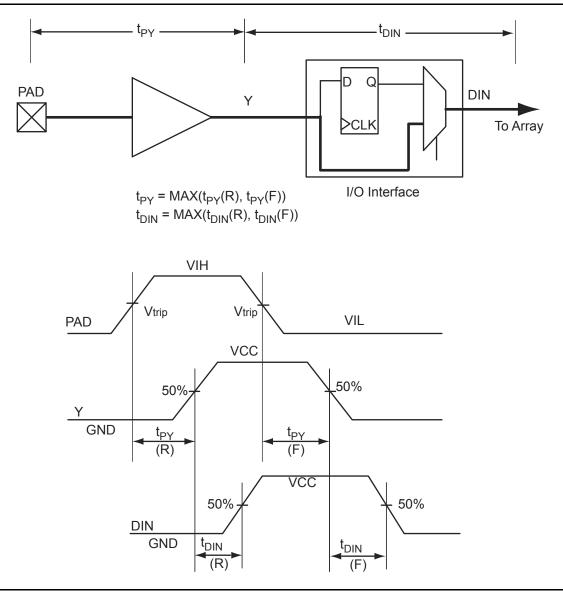


Figure 2-4 • Input Buffer Timing Model and Delays (example)

IGLOO nano Low Power Flash FPGAs

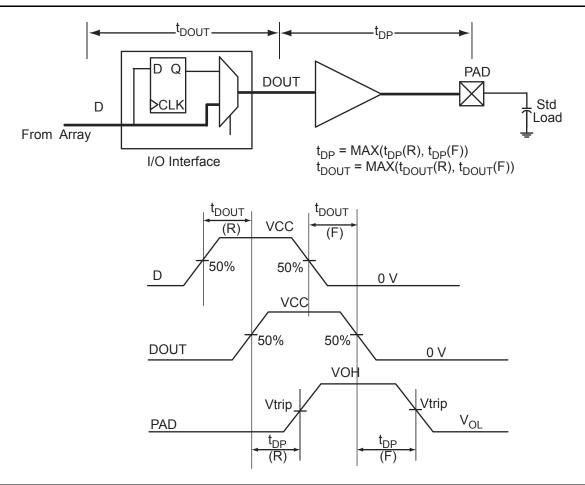


Figure 2-5 • Output Buffer Model and Delays (example)

Applies to IGLOO nano at 1.5 V Core Operating Conditions

Table 2-25 • Summary of I/O Timing Characteristics—Software Default SettingsSTD Speed Grade, Commercial-Case Conditions: TJ = 70°C, Worst-Case VCC = 1.425 V,Worst-Case VCCI = 3.0 V

I/O Standard	Drive Strength (mA)	Equivalent Software Default t Drive Strength Option ¹	Slew Rate	Capacitive Load (pF)	t _{воит}	top	t _{DIN}	t _{PY}	ters	tеоит	tzı	tzн	t _{LZ}	t _{HZ}	Units
3.3 V LVTTL / 3.3 V LVCMOS	8 mA	8 mA	High	5 pF	0.97	1.79	0.19	0.86	1.16	0.66	1.83	1.45	1.98	2.38	ns
3.3 V LVCMOS Wide Range ²	100 µA	8 mA	High	5 pF	0.97	2.56	0.19	1.20	1.66	0.66	2.57	2.02	2.82	3.31	ns
2.5 V LVCMOS	8 mA	8 mA	High	5 pF	0.97	1.81	0.19	1.10	1.24	0.66	1.85	1.63	1.97	2.26	ns
1.8 V LVCMOS	4 mA	4 mA	High	5 pF	0.97	2.08	0.19	1.03	1.44	0.66	2.12	1.95	1.99	2.19	ns
1.5 V LVCMOS	2 mA	2 mA	High	5 pF	0.97	2.39	0.19	1.19	1.52	0.66	2.44	2.24	2.02	2.15	ns

Notes:

 The minimum drive strength for any LVCMOS 1.2 V or LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.

2. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range, as specified in the JESD8-B specification.

The length of time an I/O can withstand IOSH/IOSL events depends on the junction temperature. The reliability data below is based on a 3.3 V, 8 mA I/O setting, which is the worst case for this type of analysis.

For example, at 100°C, the short current condition would have to be sustained for more than six months to cause a reliability concern. The I/O design does not contain any short circuit protection, but such protection would only be needed in extremely prolonged stress conditions.

Table 2-31 • Duration of Short Circuit Event before Failure

Temperature	Time before Failure
-40°C	> 20 years
–20°C	> 20 years
0°C	> 20 years
25°C	> 20 years
70°C	5 years
85°C	2 years
100°C	6 months

Table 2-32 • Schmitt Trigger Input Hysteresis Hysteresis Voltage Value (Typ.) for Schmitt Mode Input Buffers

Input Buffer Configuration	Hysteresis Value (typ.)
3.3 V LVTTL / LVCMOS (Schmitt trigger mode)	240 mV
2.5 V LVCMOS (Schmitt trigger mode)	140 mV
1.8 V LVCMOS (Schmitt trigger mode)	80 mV
1.5 V LVCMOS (Schmitt trigger mode)	60 mV
1.2 V LVCMOS (Schmitt trigger mode)	40 mV

Table 2-33 • I/O Input Rise Time, Fall Time, and Related I/O Reliability

Input Buffer	Input Rise/Fall Time (min.)	Input Rise/Fall Time (max.)	Reliability
LVTTL/LVCMOS (Schmitt trigger disabled)	No requirement	10 ns *	20 years (100°C)
LVTTL/LVCMOS (Schmitt trigger enabled)	No requirement	No requirement, but input noise voltage cannot exceed Schmitt hysteresis.	20 years (100°C)

Note: *The maximum input rise/fall time is related to the noise induced into the input buffer trace. If the noise is low, then the rise time and fall time of input buffers can be increased beyond the maximum value. The longer the rise/fall times, the more susceptible the input signal is to the board noise. Microsemi recommends signal integrity evaluation/characterization of the system to ensure that there is no excessive noise coupling into input signals.

Applies to 1.2 V DC Core Voltage

Table 2-43 • 3.3 V LVCMOS Wide Range Low Slew – Applies to 1.2 V DC Core VoltageCommercial-Case Conditions: TJ = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 2.7 V

Drive Strength	Equivalent Software Default Drive Strength Option ¹	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{zH}	t _{LZ}	t _{HZ}	Units
100 µA	2 mA	STD	1.55	6.01	0.26	1.31	1.91	1.10	6.01	5.66	3.02	3.49	ns
100 µA	4 mA	STD	1.55	6.01	0.26	1.31	1.91	1.10	6.01	5.66	3.02	3.49	ns
100 µA	6 mA	STD	1.55	5.02	0.26	1.31	1.91	1.10	5.02	4.76	3.38	4.10	ns
100 µA	8 mA	STD	1.55	5.02	0.26	1.31	1.91	1.10	5.02	4.76	3.38	4.10	ns

Notes:

1. The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.

2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-44 • 3.3 V LVCMOS Wide Range High Slew – Applies to 1.2 V DC Core Voltage Commercial-Case Conditions: T₁ = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 2.7 V

Drive Strength	Equivalent Software Default Drive Strength Option ¹	Speed Grade	t _{dout}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{zH}	t _{LZ}	t _{HZ}	Units
100 µA	2 mA	STD	1.55	3.82	0.26	1.31	1.91	1.10	3.82	3.15	3.01	3.65	ns
100 µA	4 mA	STD	1.55	3.82	0.26	1.31	1.91	1.10	3.82	3.15	3.01	3.65	ns
100 µA	6 mA	STD	1.55	3.25	0.26	1.31	1.91	1.10	3.25	2.61	3.38	4.27	ns
100 µA	8 mA	STD	1.55	3.25	0.26	1.31	1.91	1.10	3.25	2.61	3.38	4.27	ns

Notes:

1. The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.

2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

3. Software default selection highlighted in gray.

IGLOO nano DC and Switching Characteristics

Applies to 1.2 V DC Core Voltage

Table 2-49 • 2.5 LVCMOS Low Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 2.3 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{zH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	1.55	4.61	0.26	1.21	1.39	1.10	4.55	4.61	2.15	2.43	ns
4 mA	STD	1.55	4.61	0.26	1.21	1.39	1.10	4.55	4.61	2.15	2.43	ns
6 mA	STD	1.55	3.86	0.26	1.21	1.39	1.10	3.82	3.86	2.41	2.89	ns
8 mA	STD	1.55	3.86	0.26	1.21	1.39	1.10	3.82	3.86	2.41	2.89	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-50 • 2.5 V LVCMOS High Slew – Applies to 1.2 V DC Core Voltage Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 2.3 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{zH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	1.55	2.68	0.26	1.21	1.39	1.10	2.72	2.54	2.15	2.51	ns
4 mA	STD	1.55	2.68	0.26	1.21	1.39	1.10	2.72	2.54	2.15	2.51	ns
6 mA	STD	1.55	2.30	0.26	1.21	1.39	1.10	2.33	2.04	2.41	2.99	ns
8 mA	STD	1.55	2.30	0.26	1.21	1.39	1.10	2.33	2.04	2.41	2.99	ns

Notes:

1. Software default selection highlighted in gray.

IGLOO nano DC and Switching Characteristics

Timing Characteristics

Applies to 1.5 V DC Core Voltage

Table 2-59 • 1.5 V LVCMOS Low Slew – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.4 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	0.97	5.39	0.19	1.19	1.62	0.66	5.48	5.39	2.02	2.06	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-60 • 1.5 V LVCMOS High Slew – Applies to 1.5 V DC Core Voltage Commercial-Case Conditions: T₁ = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.4 V

			J	,				,				
Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	0.97	2.39	0.19	1.19	1.62	0.66	2.44	2.24	2.02	2.15	ns

Notes:

1. Software default selection highlighted in gray.

2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Applies to 1.2 V DC Core Voltage

Table 2-61 • 1.5 V LVCMOS Low Slew – Applies to 1.2 V DC Core Voltage Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 1.4 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	1.55	5.87	0.26	1.27	1.77	1.10	5.92	5.87	2.45	2.65	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-62 • 1.5 V LVCMOS High Slew – Applies to 1.2 V DC Core Voltage Commercial Case Conditional T = 70°C Worst Case VCC = 1.14 V

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 1.4 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	1.55	2.78	0.26	1.27	1.77	1.10	2.82	2.62	2.44	2.74	ns

Notes:

1. Software default selection highlighted in gray.

IGLOO nano DC and Switching Characteristics

1.2 V DC Core Voltage

Table 2-77 • Output Enable Register Propagation Delays Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V

Parameter	Description	Std.	Units
t _{oeclkq}	Clock-to-Q of the Output Enable Register	1.10	ns
t _{OESUD}	Data Setup Time for the Output Enable Register	1.15	ns
t _{OEHD}	Data Hold Time for the Output Enable Register	0.00	ns
t _{OECLR2Q}	Asynchronous Clear-to-Q of the Output Enable Register	1.65	ns
t _{OEPRE2Q}	Asynchronous Preset-to-Q of the Output Enable Register	1.65	ns
t _{OEREMCLR}	Asynchronous Clear Removal Time for the Output Enable Register	0.00	ns
t _{OERECCLR}	Asynchronous Clear Recovery Time for the Output Enable Register	0.24	ns
t _{OEREMPRE}	Asynchronous Preset Removal Time for the Output Enable Register	0.00	ns
t _{OERECPRE}	Asynchronous Preset Recovery Time for the Output Enable Register	0.24	ns
tOEWCLR	Asynchronous Clear Minimum Pulse Width for the Output Enable Register	0.19	ns
t _{OEWPRE}	Asynchronous Preset Minimum Pulse Width for the Output Enable Register	0.19	ns
t _{OECKMPWH}	Clock Minimum Pulse Width HIGH for the Output Enable Register	0.31	ns
t _{OECKMPWL}	Clock Minimum Pulse Width LOW for the Output Enable Register	0.28	ns



IGLOO nano DC and Switching Characteristics

Global Tree Timing Characteristics

Global clock delays include the central rib delay, the spine delay, and the row delay. Delays do not include I/O input buffer clock delays, as these are I/O standard–dependent, and the clock may be driven and conditioned internally by the CCC module. For more details on clock conditioning capabilities, refer to the "Clock Conditioning Circuits" section on page 2-70. Table 2-88 to Table 2-96 on page 2-68 present minimum and maximum global clock delays within each device. Minimum and maximum delays are measured with minimum and maximum loading.

Timing Characteristics

1.5 V DC Core Voltage

Table 2-88 •AGLN010 Global Resource
Commercial-Case Conditions: T_J = 70°C, VCC = 1.425 V

			Std.	
Parameter	Description	Min. ¹	Max. ²	Units
t _{RCKL}	Input Low Delay for Global Clock	1.13	1.42	ns
t _{RCKH}	Input High Delay for Global Clock	1.15	1.50	ns
t _{RCKMPWH}	Minimum Pulse Width HIGH for Global Clock	1.40		ns
t _{RCKMPWL}	Minimum Pulse Width LOW for Global Clock	1.65		ns
t _{RCKSW}	Maximum Skew for Global Clock		0.35	ns

Notes:

1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).

2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).

3. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-89 • AGLN015 Global Resource Commercial-Case Conditions: T₁ = 70°C, VCC = 1.425 V

			Std.		
Parameter	Description	-	Min. ¹	Max. ²	Units
t _{RCKL}	Input Low Delay for Global Clock		1.21	1.55	ns
t _{RCKH}	Input High Delay for Global Clock		1.23	1.65	ns
t _{RCKMPWH}	Minimum Pulse Width HIGH for Global Clock		1.40		ns
t _{RCKMPWL}	Minimum Pulse Width LOW for Global Clock		1.65		ns
t _{RCKSW}	Maximum Skew for Global Clock			0.42	ns

Notes:

1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).

2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).

Table 2-101 • IGLOO nano CCC/PLL Specification	
For IGLOO nano V2 Devices, 1.2 V DC Core Supply Voltage	

Parameter		Min.	Тур.	Max.	Units
Clock Conditioning Circuitry Input Frequency fIN_CCC				160	MHz
Clock Conditioning Circuitry Output Frequency fOUT_CC	0.75		160	MHz	
Delay Increments in Programmable Delay Blocks ^{1, 2}			580 ³		ps
Number of Programmable Values in Each Programmab	le Delay Block			32	
Serial Clock (SCLK) for Dynamic PLL ^{4,9}				60	
Input Cycle-to-Cycle Jitter (peak magnitude)				0.25	ns
Acquisition Time					
	LockControl = 0			300	μs
	LockControl = 1			6.0	ms
Tracking Jitter ⁵					
	LockControl = 0			4	ns
	LockControl = 1			3	ns
Output Duty Cycle		48.5		51.5	%
Delay Range in Block: Programmable Delay 1 ^{1, 2}		2.3		20.86	ns
Delay Range in Block: Programmable Delay 2 ^{1, 2}		0.025		20.86	ns
Delay Range in Block: Fixed Delay ^{1, 2}			5.7		ns
VCO Output Peak-to-Peak Period Jitter F _{CCC_OUT} ⁶		Max Pe	ak-to-Peal	<pre> Period Jitte </pre>	er ^{6,7,8}
-	$SSO \le 2$	$SSO \leq 4$	$\text{SSO} \leq 8$	$SSO \leq 16$	
0.75 MHz to 50MHz	0.50	1.20	2.00	3.00	%
50 MHz to 100 MHz	2.50	5.00	7.00	15.00	%

Notes:

1. This delay is a function of voltage and temperature. See Table 2-6 on page 2-6 and Table 2-7 on page 2-7 for deratings.

2. $T_J = 25^{\circ}C$, $V_{CC} = 1.2 V$.

- 3. When the CCC/PLL core is generated by Microsemi core generator software, not all delay values of the specified delay increments are available. Refer to the Libero SoC Online Help associated with the core for more information.
- 4. Maximum value obtained for a STD speed grade device in Worst-Case Commercial conditions. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 and Table 2-7 on page 2-7 for derating values.
- 5. Tracking jitter is defined as the variation in clock edge position of PLL outputs with reference to the PLL input clock edge. Tracking jitter does not measure the variation in PLL output period, which is covered by the period jitter parameter.
- 6. VCO output jitter is calculated as a percentage of the VCO frequency. The jitter (in ps) can be calculated by multiplying the VCO period by the % jitter. The VCO jitter (in ps) applies to CCC_OUT, regardless of the output divider settings. For example, if the jitter on VCO is 300 ps, the jitter on CCC_OUT is also 300 ps, no matter what the settings are for the output divider.
- 7. Measurements done with LVTTL 3.3 V 8 mA I/O drive strength and high slew rate. VCC/VCCPLL = 1.14 V, VCCI = 3.3 V, VQ/PQ/TQ type of packages, 20 pF load.
- SSOs are outputs that are synchronous to a single clock domain and have their clock-to-out times within ±200 ps of each other. Switching I/Os are placed outside of the PLL bank. Refer to the "Simultaneously Switching Outputs (SSOs) and Printed Circuit Board Layout" section in the IGLOO nano FPGA Fabric User's Guide.
- 9. The AGLN010, AGLN015, and AGLN020 devices do not support PLLs.

Timing Characteristics

Maximum Frequency for FIFO

1.5 V DC Core Voltage

Table 2-106 • FIFO

 $\mathsf{F}_{\mathsf{MAX}}$

Worst Commercial-Case Conditions: T_J = 70°C, VCC = 1.425 V Parameter Units Description Std. REN, WEN Setup Time 1.66 ns t_{ENS} REN, WEN Hold Time 0.13 t_{ENH} ns **BLK Setup Time** 0.30 ns t_{BKS} **BLK Hold Time** 0.00 ns t_{BKH} Input Data (WD) Setup Time 0.63 ns t_{DS} Input Data (WD) Hold Time 0.20 t_{DH} ns Clock High to New Data Valid on RD (flow-through) 2.77 ns t_{CKQ1} Clock High to New Data Valid on RD (pipelined) 1.50 ns t_{CKQ2} RCLK High to Empty Flag Valid 2.94 ns t_{RCKEF} WCLK High to Full Flag Valid 2.79 ns t_{WCKFF} Clock High to Almost Empty/Full Flag Valid 10.71 ns t_{CKAF} RESET Low to Empty/Full Flag Valid 2.90 ns t_{RSTFG} RESET Low to Almost Empty/Full Flag Valid 10.60 t_{RSTAF} ns RESET Low to Data Out LOW on RD (flow-through) 1.68 ns t_{RSTBQ} RESET Low to Data Out LOW on RD (pipelined) 1.68 ns **RESET Removal** 0.51 ns t_{REMRSTB} **RESET Recovery** 2.68 **t**_{RECRSTB} ns **RESET Minimum Pulse Width** 0.68 ns t_{MPWRSTB} Clock Cycle Time t_{CYC} 6.24 ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

160

MHz

IGLOO nano DC and Switching Characteristics

1.2 V DC Core Voltage

Table 2-107 • FIFO

Worst Commercial-Case Conditions: T_J = 70°C, VCC = 1.14 V

Parameter	Description	Std.	Units
t _{ENS}	REN, WEN Setup Time	3.44	ns
t _{ENH}	REN, WEN Hold Time	0.26	ns
t _{BKS}	BLK Setup Time	0.30	ns
t _{BKH}	BLK Hold Time	0.00	ns
t _{DS}	Input Data (DI) Setup Time	1.30	ns
t _{DH}	Input Data (DI) Hold Time	0.41	ns
t _{CKQ1}	Clock High to New Data Valid on RD (flow-through)	5.67	ns
t _{CKQ2}	Clock High to New Data Valid on RD (pipelined)	3.02	ns
t _{RCKEF}	RCLK High to Empty Flag Valid	6.02	ns
t _{WCKFF}	WCLK High to Full Flag Valid	5.71	ns
t _{CKAF}	Clock High to Almost Empty/Full Flag Valid	22.17	ns
t _{RSTFG}	RESET LOW to Empty/Full Flag Valid	5.93	ns
t _{RSTAF}	RESET LOW to Almost Empty/Full Flag Valid	21.94	ns
t _{RSTBQ}	RESET LOW to Data Out Low on RD (flow-through)	3.41	ns
	RESET LOW to Data Out Low on RD (pipelined)	4.09	3.41
t _{REMRSTB}	RESET Removal	1.02	ns
t _{RECRSTB}	RESET Recovery	5.48	ns
t _{MPWRSTB}	RESET Minimum Pulse Width	1.18	ns
t _{CYC}	Clock Cycle Time	10.90	ns
F _{MAX}	Maximum Frequency for FIFO	92	MHz

TDI

Table 3-3 • TRST and TCK Pull-Down Recommendations

VJTAG	Tie-Off Resistance*
VJTAG at 3.3 V	200 Ω to 1 kΩ
VJTAG at 2.5 V	200 Ω to 1 kΩ
VJTAG at 1.8 V	500 Ω to 1 kΩ
VJTAG at 1.5 V	500 Ω to 1 kΩ

Note: Equivalent parallel resistance if more than one device is on the JTAG chain

Test Data Input

Serial input for JTAG boundary scan, ISP, and UJTAG usage. There is an internal weak pull-up resistor on the TDI pin.

TDO Test Data Output

Serial output for JTAG boundary scan, ISP, and UJTAG usage.

TMS Test Mode Select

The TMS pin controls the use of the IEEE 1532 boundary scan pins (TCK, TDI, TDO, TRST). There is an internal weak pull-up resistor on the TMS pin.

TRST Boundary Scan Reset Pin

The TRST pin functions as an active-low input to asynchronously initialize (or reset) the boundary scan circuitry. There is an internal weak pull-up resistor on the TRST pin. If JTAG is not used, an external pull-down resistor could be included to ensure the test access port (TAP) is held in reset mode. The resistor values must be chosen from Table 3-2 and must satisfy the parallel resistance value requirement. The values in Table 3-2 correspond to the resistor recommended when a single device is used, and the equivalent parallel resistor when multiple devices are connected via a JTAG chain.

In critical applications, an upset in the JTAG circuit could allow entrance to an undesired JTAG state. In such cases, Microsemi recommends tying off TRST to GND through a resistor placed close to the FPGA pin.

Note that to operate at all VJTAG voltages, 500 Ω to 1 k Ω will satisfy the requirements.

Special Function Pins

NC

No Connect

This pin is not connected to circuitry within the device. These pins can be driven to any voltage or can be left floating with no effect on the operation of the device.

DC

Do Not Connect

This pin should not be connected to any signals on the PCB. These pins should be left unconnected.

Packaging

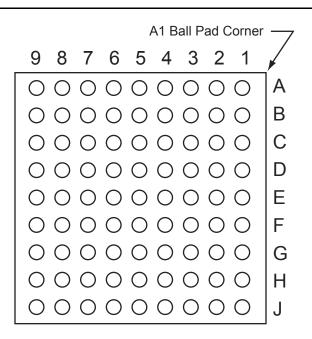
Semiconductor technology is constantly shrinking in size while growing in capability and functional integration. To enable next-generation silicon technologies, semiconductor packages have also evolved to provide improved performance and flexibility.

Microsemi consistently delivers packages that provide the necessary mechanical and environmental protection to ensure consistent reliability and performance. Microsemi IC packaging technology efficiently supports high-density FPGAs with large-pin-count Ball Grid Arrays (BGAs), but is also flexible enough to accommodate stringent form factor requirements for Chip Scale Packaging (CSP). In addition, Microsemi offers a variety of packages designed to meet your most demanding application and economic requirements for today's embedded and mobile systems.



Package Pin Assignments

CS81



Note: This is the bottom view of the package.

Note

For Package Manufacturing and Environmental information, visit the Resource Center at http://www.microsemi.com/soc/products/solutions/package/docs.aspx.



Datasheet Information

Revision / Version	Changes	Page
Revision 2 (Dec 2008) Product Brief Advance v0.4	The second table note in "IGLOO nano Devices" table was revised to state, "AGLN060, AGLN125, and AGLN250 in the CS81 package do not support PLLs. AGLN030 and smaller devices do not support this feature."	II
	The I/Os per package for CS81 were revised to 60 for AGLN060, AGLN125, and AGLN250 in the "I/Os Per Package"table.	II
Packaging Advance v0.3	The "UC36" pin table is new.	4-2
Revision 1 (Nov 2008) Product Brief Advance v0.3	The "Advanced I/Os" section was updated to include wide power supply voltage support for 1.14 V to 1.575 V.	Ι
	The AGLN030 device was added to product tables and replaces AGL030 entries that were formerly in the tables.	VI
	The "I/Os Per Package"table was updated for the CS81 package to change the number of I/Os for AGLN060, AGLN125, and AGLN250 from 66 to 64.	II
	The "Wide Range I/O Support" section is new.	1-8
	The table notes and references were revised in Table 2-2 • Recommended Operating Conditions ¹ . VMV was included with VCCI and a table note was added stating, "VMV pins must be connected to the corresponding VCCI pins. See <i>Pin Descriptions</i> for further information." Please review carefully.	2-2
	VJTAG was added to the list in the table note for Table 2-9 • Quiescent Supply Current (IDD) Characteristics, IGLOO nano Flash*Freeze Mode*. Values were added for AGLN010, AGLN015, and AGLN030 for 1.5 V.	2-7
	VCCI was removed from the list in the table note for Table 2-10 • Quiescent Supply Current (IDD) Characteristics, IGLOO nano Sleep Mode*.	2-8
	Values for I _{CCA} current were updated for AGLN010, AGLN015, and AGLN030 in Table 2-12 • Quiescent Supply Current (IDD), No IGLOO nano Flash*Freeze Mode ¹ .	2-8
	Values for PAC1 and PAC2 were added to Table 2-15 • Different Components Contributing to Dynamic Power Consumption in IGLOO nano Devices and Table 2-17 • Different Components Contributing to Dynamic Power Consumption in IGLOO nano Devices.	2-10, 2-11
	Table notes regarding wide range support were added to Table 2-21 • Summary of Maximum and Minimum DC Input and Output Levels.	2-19
	1.2 V LVCMOS wide range values were added to Table 2-22 • Summary of Maximum and Minimum DC Input Levels and Table 2-23 • Summary of AC Measuring Points.	2-19, 2-20
	The following table note was added to Table 2-25 • Summary of I/O Timing Characteristics—Software Default Settings and Table 2-26 • Summary of I/O Timing Characteristics—Software Default Settings: "All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range, as specified in the JESD8-B specification."	2-21
	3.3 V LVCMOS Wide Range and 1.2 V Wide Range were added to Table 2-28 • I/O Output Buffer Maximum Resistances ¹ andTable 2-30 • I/O Short Currents IOSH/IOSL.	2-23, 2-24